

## ACPL-M417T

### Automotive Low-Power, High-Gain Optocoupler with Transistor Output

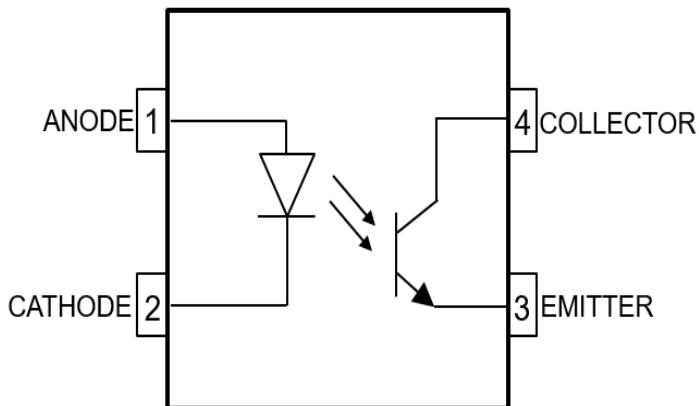
#### Description

The Broadcom<sup>®</sup> ACPL-M417T is a single-channel low-speed optocoupler with transistor output. The ACPL-M417T comes in a compact, surface-mountable SO4 package for space savings. It provides an isolation voltage of 4 kV<sub>RMS</sub> between input and output channels.

The ACPL-M417T is primarily designed for low-power operation, with low-operating LED drive current of 0.3 mA for low-speed signaling. The low collector dark current effectively does not consume any current when not in use.

Broadcom R<sup>2</sup>Coupler™ isolation products provide reinforced insulation and reliability that delivers safe signal isolation critical in automotive and high temperature industrial applications.

#### Functional Diagram



**CAUTION!** It is advised that normal static precautions be taken in handling and assembly of this component to prevent damage and/or degradation which may be induced by ESD. The components featured in this data sheet are not to be used in military or aerospace applications or environments.

#### Features

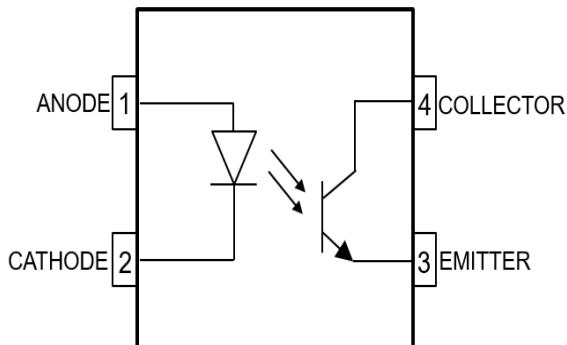
- Qualified to AEC-Q101 Test Guidelines
- Automotive temperature range:  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$
- Specifications across full temperature range
- $BV_{\text{CEO}}$  min. of 80V
- Low  $I_{\text{F}}$  drive of 0.3 mA
- Tight CTR range
- Single channel in SO4 package with 5 mm creepage and clearance
- Regulatory approvals:
  - UL1577 4 kV<sub>RMS</sub> for 1 minute
  - CSA approval
  - IEC/EN 60747-5-5  $V_{\text{IORM}} = 567 V_{\text{PEAK}}$

#### Applications

- Electric Vehicle Powertrain
- DC-DC Converter
- EV/PHEV Charger
- HVAC
- Fault reporting modules

## Package Pin Out

Figure 1: Pin Out



## Pin Description

| Pin Number | Name | Function  |
|------------|------|-----------|
| 1          | AN   | Anode     |
| 2          | CA   | Cathode   |
| 3          | E    | Emitter   |
| 4          | C    | Collector |

## Ordering Information

| Part Number | Option<br>(RoHS Compliant) | Package | Surface<br>Mount | Tape and<br>Reel | UL 4000 $V_{rms}$ /<br>1 Minute Rating | IEC/EN<br>60747-5-5 | Quantity      |
|-------------|----------------------------|---------|------------------|------------------|--|---------------------|---------------|
| ACPL-M417T  | -000E                      | SO4     | X                | —                | X                                      | —                   | 100 per tube  |
|             | -500E                      |         | X                | X                | X                                      | —                   | 1500 per reel |
|             | -560E                      |         | X                | X                | X                                      | X                   | 1500 per reel |

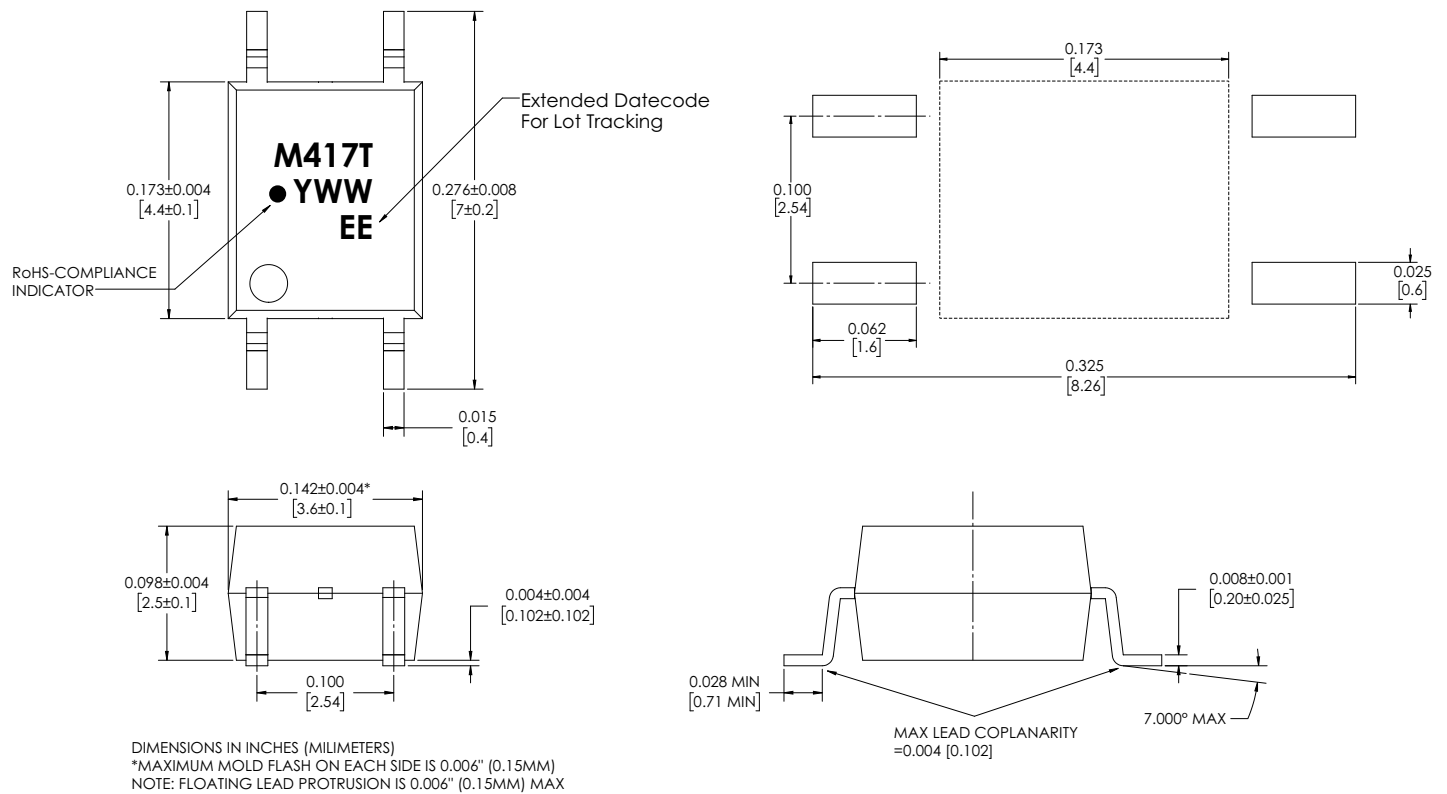
To order, choose a part number from the part number column and combine it with the desired option from the option column to form an order entry.

**Example:** ACPL-M417T-560E to order the product of SO4 Surface Mount package in Tape and Reel packaging with IEC/EN 60747-5-5 Safety Approval in RoHS compliant.

Options data sheets are available. Contact your Broadcom sales representative or an authorized distributor for information.

# Package Outline Drawing

Figure 2: Small Outline SO4 Package



## Recommended PB-Free IR Profile

Recommended reflow condition as per JEDEC Standard, J-STD-020 (latest revision).

**NOTE:** Use non-halide flux.

## Regulatory Information

The ACPL-M417T is approved by the following organizations:

|        |   |
|--------|---|
| UL     | UL 1577, component recognition program up to $V_{ISO} = 4000 V_{RMS}$       |
| CSA    | CAN/CSA-C22.2 No. 62368-1   |
| IEC/EN | IEC/EN 60747-5-5<br>$V_{IORM} = 567 V_{PEAK}$<br>$V_{IOTM} = 6000 V_{PEAK}$ |

## IEC/EN 60747-5-5 Insulation Characteristics

| Description  | Symbol                                     | Characteristic    | Unit                    |
|--|--|-------------------|-------------------------|
| Installation classification per DIN VDE 0110/1.89, Table 1<br>For Rated Mains Voltage $\leq 150 V_{rms}$<br>For Rated Mains Voltage $\leq 300 V_{rms}$ | —<br>—                                     | I – IV<br>I – III | —<br>—                  |
| Climatic Classification  | —  | 40/125/21         | —                       |
| Pollution Degree (DIN VDE 0110/1.89)   | —  | 2                 | —                       |
| Maximum Working Insulation Voltage   | $V_{IORM}$                                 | 567               | $V_{PEAK}$              |
| Input to Output Test Voltage, Method b<br>$V_{IORM} \times 1.875 = V_{PR}$ , 100% Production Test with $t_m = 1$ second, Partial discharge $< 5$ pC    | $V_{PR}$                                   | 1063              | $V_{PEAK}$              |
| Input to Output Test Voltage, Method a<br>$V_{IORM} \times 1.6 = V_{PR}$ , Type and Sample Test, $t_m = 10$ seconds, Partial discharge $< 5$ pC        | $V_{PR}$                                   | 907               | $V_{PEAK}$              |
| Highest Allowable Overvoltage<br>(Transient Overvoltage $t_{ini} = 60$ seconds)  | $V_{IOTM}$                                 | 6000              | $V_{PEAK}$              |
| Safety-limiting values – maximum values allowed in the event of a failure<br>Case Temperature<br>Input Current<br>Output Power                         | $T_S$<br>$I_{S, INPUT}$<br>$P_{S, OUTPUT}$ | 175<br>150<br>600 | $^{\circ}C$<br>mA<br>mW |
| Insulation Resistance at $T_S$ , $V_{IO} = 500V$   | $R_S$                                      | $>10^9$           | $\Omega$                |

## Insulation and Safety Related Specifications

| Parameter  | Symbol | Value  | Units | Conditions  |
|--|--------|--------|-------|---|
| Minimum External Air Gap (Clearance)                 | L(101) | 5      | mm    | Measured from input terminals to output terminals, shortest distance through air.   |
| Minimum External Tracking (Creepage)                 | L(102) | 5      | mm    | Measured from input terminals to output terminals, shortest distance path along body.   |
| Minimum Internal Plastic Gap<br>(Internal Clearance) | —      | 0.08   | mm    | Through insulation, distance conductor to conductor, usually the straight-line distance thickness between the emitter and detector. |
| Tracking Resistance<br>(Comparative Tracking Index)  | CTI    | $>175$ | V     | DIN IEC 112/VDE 0303 Part 1   |
| Isolation Group                                      | —      | IIIa   | —     | Material Group (DIN VDE 0110)   |

## Absolute Maximum Ratings

| Parameter  | Symbol        | Min. | Max. | Units | Note |
|--|---------------|------|------|-------|------|
| Storage Temperature  | $T_S$         | -55  | 150  | °C    |      |
| Operating Ambient Temperature                                    | $T_A$         | -40  | 125  | °C    |      |
| IC Junction Temperature  | $T_J$         | —    | 150  | °C    | a    |
| Average Forward Input Current                                    | $I_{F(AVG)}$  | —    | 5    | mA    |      |
| Peak Forward Input Current<br>(50% duty cycle, 1 ms pulse width) | $I_{F(PEAK)}$ | —    | 10   | mA    |      |
| Reverse Input Voltage ( $V_{CA} - V_{AN}$ )                      | $V_R$         | —    | 6    | V     |      |
| Collector Emitter Voltage  | $V_{CE}$      | -6   | 80   | V     |      |
| Continuous Collector Current                                     | $I_C$         | —    | 50   | mA    |      |
| Peak Collector Current   | $I_{C(PEAK)}$ | —    | 100  | mA    |      |
| Input Power Dissipation  | $P_{IN}$      | —    | 20   | mW    |      |
| Output Power Dissipation   | $P_O$         | —    | 300  | mW    | a    |

a. Total power dissipation is derated linearly above 95°C at a rate of 5 mW/°C. Maximum LED and detector junction temperature must not exceed 150°C.

## Recommended Operating Conditions

| Parameter  | Symbol       | Min. | Max. | Unit | Note |
|--|--------------|------|------|------|------|
| Operating Ambient Temperature                    | $T_A$        | -40  | 125  | °C   |      |
| Collector Emitter Voltage                        | $V_{CE}$     | —    | 48   | V    |      |
| Input LED Turn on Current (ON)                   | $I_{F(ON)}$  | 0.3  | 1.5  | mA   |      |
| Input LED Turn off Voltage ( $V_{AN} - V_{CA}$ ) | $V_{F(OFF)}$ | -5.5 | 0.4  | V    |      |
| Collector Current                                | $I_C$        | —    | 20   | mA   | a    |

a. Not to exceed absolute maximum rating of 300 mW.

## Electrical Specifications (DC)

Unless otherwise specified, all minimum/maximum specifications are at recommended operating conditions. All typical values are at  $T_A = 25^\circ\text{C}$ ,  $V_{CE} = 5\text{V}$ .

| Parameter   | Symbol                    | Min. | Typ. | Max. | Unit          | Test Conditions   | Fig. | Notes |
|---|---------------------------|------|------|------|---------------|---|------|-------|
| LED Forward Voltage ( $V_{AN} - V_{CA}$ )           | $V_F$                     | 1.0  | 1.4  | 1.7  | V             | $I_F = 0.5\text{ mA}$   | 4    |       |
| Temperature Coefficient of LED Forward Voltage      | $\Delta V_F / \Delta T_A$ | —    | -1.2 | —    | mV/°C         | $I_F = 0.5\text{ mA}$   |      |       |
| LED Reverse Breakdown Voltage ( $V_{CA} - V_{AN}$ ) | $V_{BR}$                  | 6    | —    | —    | V             | $I_F = -100\ \mu\text{A}$   |      |       |
| LED Input Capacitance                               | $C_{IN}$                  | —    | 8    | —    | pF            | $V_F = 0\text{V}$   |      |       |
| Collector Emitter Breakdown Voltage                 | $BV_{CEO}$                | 80   | —    | —    | V             | $I_C = 0.5\text{ mA}$ ,<br>$I_F = 0\text{ mA}$ ,<br>$T_A = 25^\circ\text{C}$  |      |       |
| Emitter Collector Breakdown Voltage                 | $BV_{ECO}$                | 6    | 10   | —    | V             | $I_E = 0.1\text{ mA}$ ,<br>$I_F = 0\text{ mA}$ ,<br>$T_A = 25^\circ\text{C}$  |      |       |
| Collector Dark Current                              | $I_{CEO}$                 | —    | 0.02 | 100  | $\mu\text{A}$ | $I_F = 0\text{ mA}$ , $V_{CE} = 48\text{V}$                                   | 6    |       |
|   |                           | —    | —    | 50   | $\mu\text{A}$ | $I_F = 0\text{ mA}$ , $V_{CE} = 10\text{V}$                                   |      |       |
| Current Transfer Ratio                              | CTR                       | 3300 | 5000 | 6600 | %             | $I_F = 0.5\text{ mA}$ ,<br>$V_{CE} = 2\text{V}$ ,<br>$T_A = 25^\circ\text{C}$ |      | a     |
|   |                           | 3300 | 5000 | 6600 | %             | $I_F = 0.5\text{ mA}$ ,<br>$V_{CE} = 5\text{V}$ ,<br>$T_A = 25^\circ\text{C}$ |      | a     |
|   |                           | 1600 | 5000 | 6800 | %             | $I_F = 0.5\text{ mA}$ ,<br>$V_{CE} = 5\text{V}$                               |      | a     |
|   |                           | 3500 | 5100 | 7000 | %             | $I_F = 1\text{ mA}$ ,<br>$V_{CE} = 5\text{V}$ ,<br>$T_A = 25^\circ\text{C}$   |      | a     |
| Saturated Current Transfer Ratio                    | $CTR_{SAT}$               | 1000 | —    | —    | %             | $I_F = 0.5\text{ mA}$ ,<br>$V_{CE} = 0.4\text{V}$                             |      | a     |
|   |                           | 1000 | —    | —    | %             | $I_F = 1\text{ mA}$ , $V_{CE} = 0.4\text{V}$                                  |      | a     |
| Saturated Voltage                                   | $V_{CE(SAT)}$             | —    | 0.1  | 0.4  | V             | $I_F = 0.5\text{ mA}$ , $I_C = 5\text{ mA}$                                   | 12   |       |
|   |                           | —    | 0.1  | 0.4  | V             | $I_F = 1\text{ mA}$ , $I_C = 10\text{ mA}$                                    | 12   |       |
| Output Capacitance                                  | $C_{CE}$                  | —    | 8    | —    | pF            | $V_{CE} = 0\text{V}$ , $f = 1\text{ MHz}$                                     |      |       |
| Cut-off Frequency (-3 dB)                           | $f_C$                     | —    | 100  | —    | kHz           | $V_{CC} = 5\text{V}$ ,<br>$I_F = 0.5\text{ mA}$ ,<br>$R_L = 100\ \Omega$      |      |       |

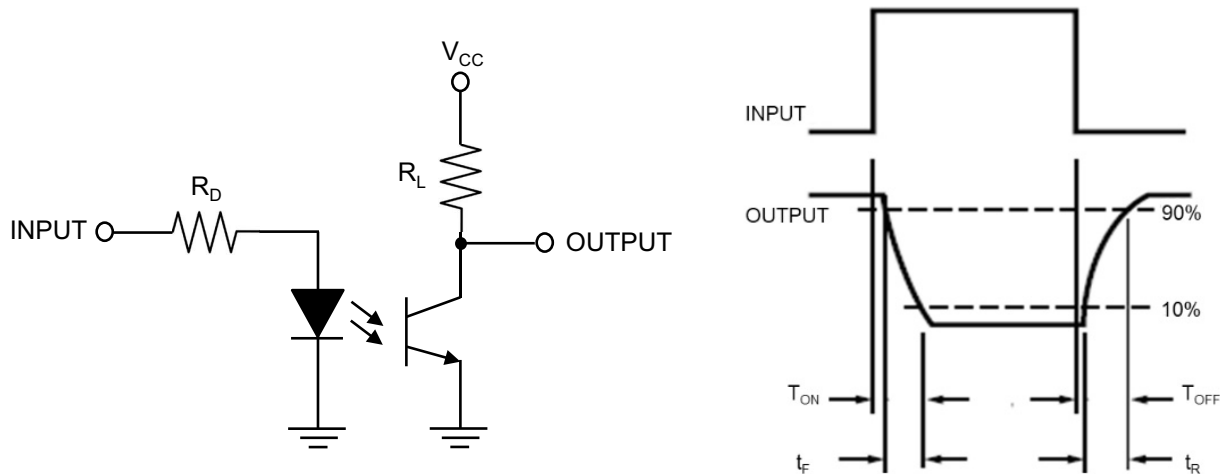
a. Current Transfer Ratio in percent is defined as the ratio of output collector current,  $I_C$ , to the forward LED input current,  $I_F$ , times 100.

## Switching Specifications (AC)

Unless otherwise specified, all minimum/maximum specifications are at recommended operating conditions. All typical values at  $T_A = 25^\circ\text{C}$ ,  $V_{CE} = 5\text{V}$ .

| Parameter                     | Symbol    | Min. | Typ. | Max. | Unit          | Test Conditions   | Fig.      | Notes     |
|-------------------------------|-----------|------|------|------|---------------|---|-----------|-----------|
| Turn-on Time                  | $t_{ON}$  | —    | 2    | —    | $\mu\text{s}$ | $I_F = 0.5\text{ mA}$ ,<br>$V_{CC} = 5\text{V}$ ,<br>$R_L = 2\text{ k}\Omega$ | 3, 13, 15 |           |
| Turn-off Time                 | $t_{OFF}$ | —    | 40   | —    | $\mu\text{s}$ |   |           | 3, 14, 16 |
| Output Fall Time (90% to 10%) | $t_F$     | —    | 1.2  | —    | $\mu\text{s}$ |   |           |           |
| Output Rise Time (10% to 90%) | $t_R$     | —    | 20   | —    | $\mu\text{s}$ |   |           |           |
| Turn-on Time                  | $t_{ON}$  | —    | 2    | —    | $\mu\text{s}$ | $I_F = 0.5\text{ mA}$ ,<br>$V_{CC} = 5\text{V}$ ,<br>$R_L = 750\Omega$        | 3, 13, 15 |           |
| Turn-off Time                 | $t_{OFF}$ | —    | 30   | —    | $\mu\text{s}$ |   |           | 3, 14, 16 |
| Output Fall Time (90% to 10%) | $t_F$     | —    | 1.2  | —    | $\mu\text{s}$ |   |           |           |
| Output Rise Time (10% to 90%) | $t_R$     | —    | 10   | —    | $\mu\text{s}$ |   |           |           |

Figure 3: Test Circuit for Response Time

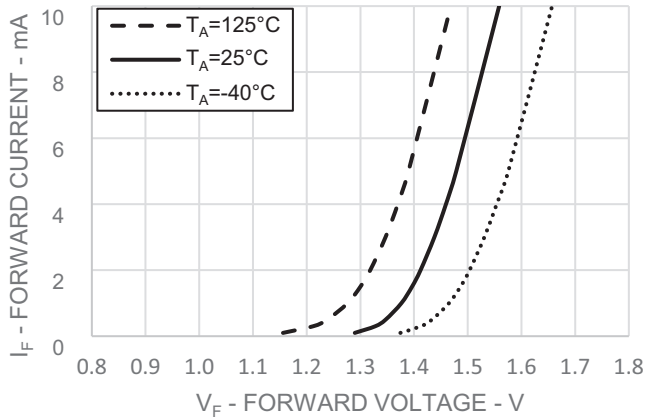


## Package Characteristics

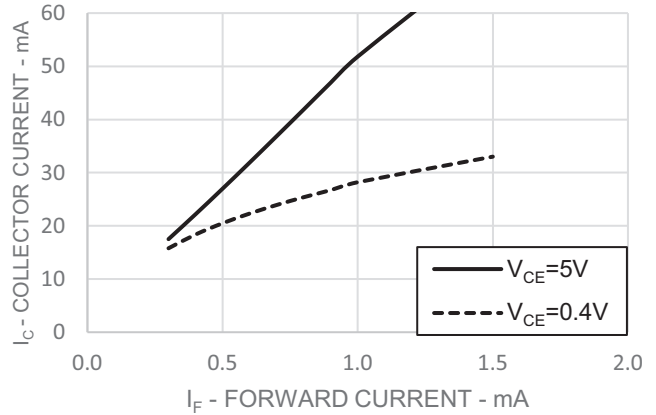
| Parameter                                | Symbol    | Min. | Typ.      | Max. | Unit        | Test Conditions   | Note |
|--|-----------|------|-----------|------|-------------|---|------|
| Input-Output Momentary Withstand Voltage | $V_{ISO}$ | 4000 | —         | —    | $V_{RMS}$   | $RH < 50\%$ , $t = 1\text{ min.}$<br>$T_A = 25^\circ\text{C}$ |      |
| Resistance (Input-Output)                | $R_{I-O}$ | —    | $10^{12}$ | —    | $\Omega$    | $V_{I-O} = 500\text{ V}_{DC}$                                 |      |
| Capacitance (Input-Output)               | $C_{I-O}$ | —    | 0.8       | —    | $\text{pF}$ | $f = 1\text{ MHz}$  |      |

# Typical Characteristics Plots and Test Conditions

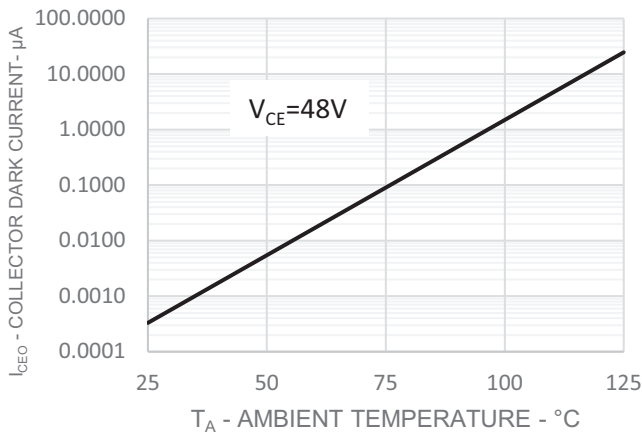
**Figure 4: Forward Current vs. Forward Voltage**



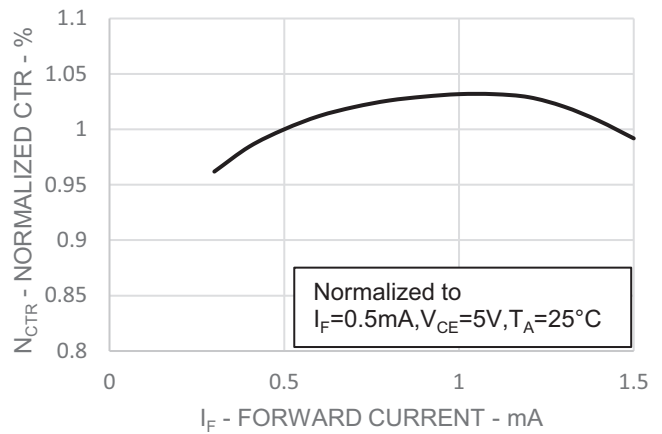
**Figure 5: Collector Current vs. Forward Current**



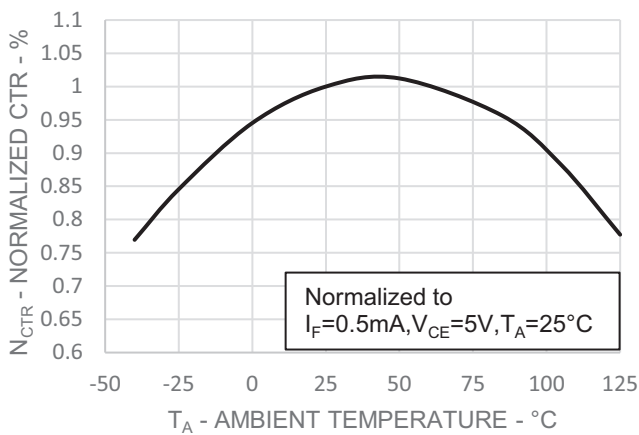
**Figure 6: Collector Dark Current vs. Ambient Temperature**



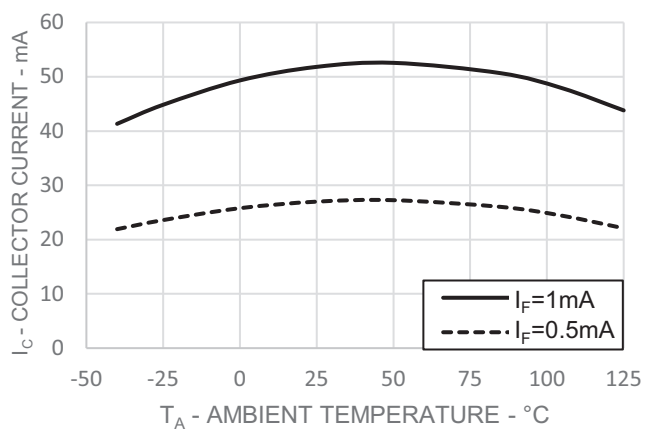
**Figure 7: Normalized CTR vs. Forward Current**



**Figure 8: Normalized CTR vs. Ambient Temperature**

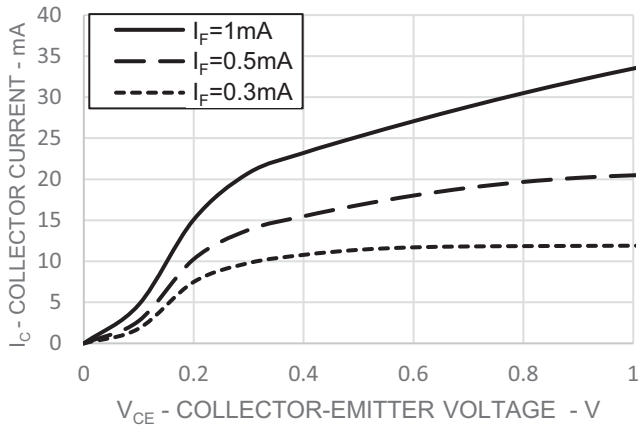


**Figure 9: Collector Current vs. Ambient Temperature**

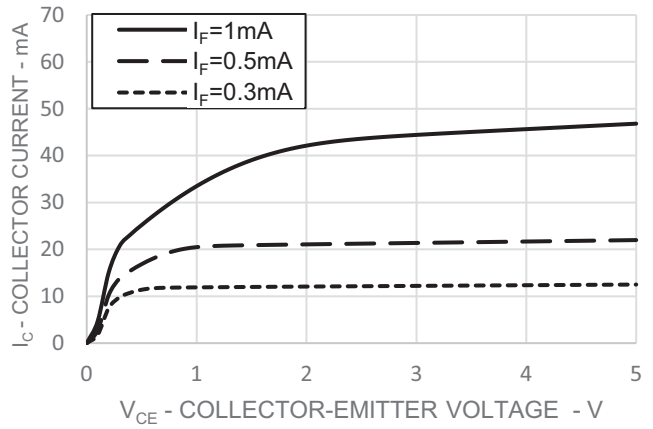




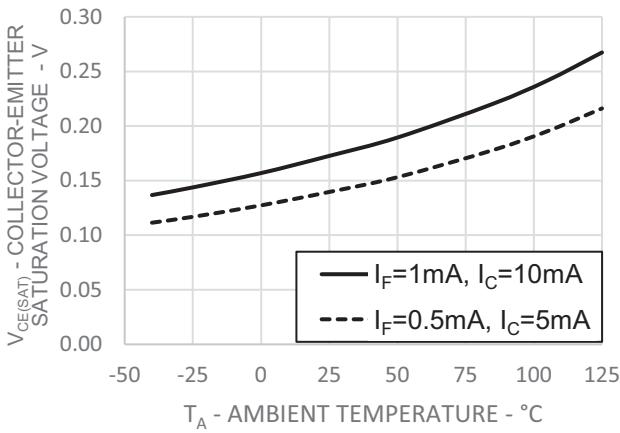
**Figure 10: Collector Current vs. Small Collector-Emitter Voltage**



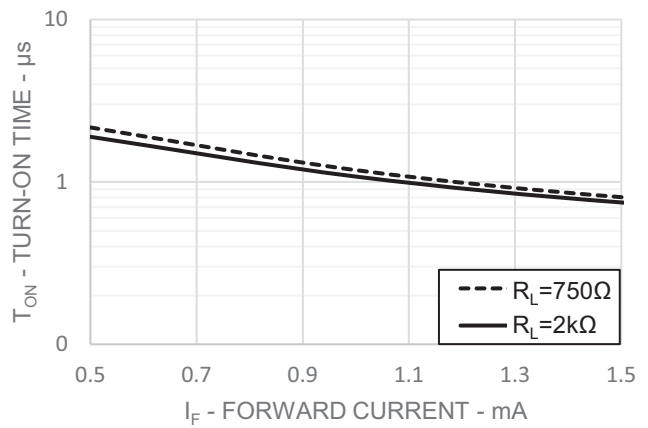
**Figure 11: Collector Current vs. Collector-Emitter Voltage**



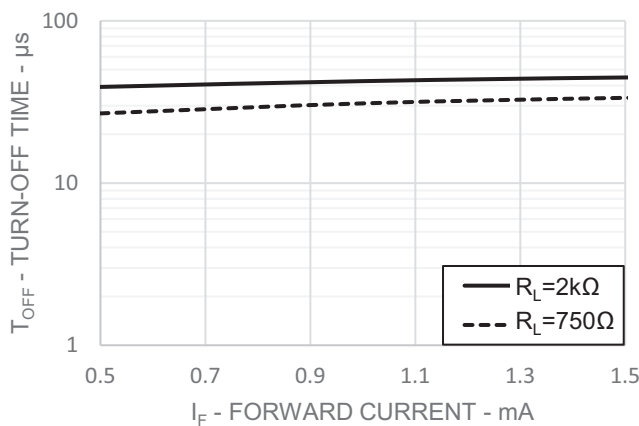
**Figure 12: Collector-Emitter Saturation Voltage vs. Ambient Temperature**



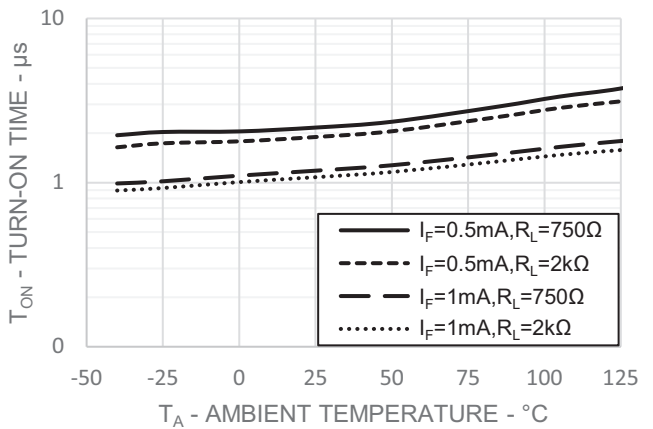
**Figure 13: Turn-On Time vs. Load Resistance**



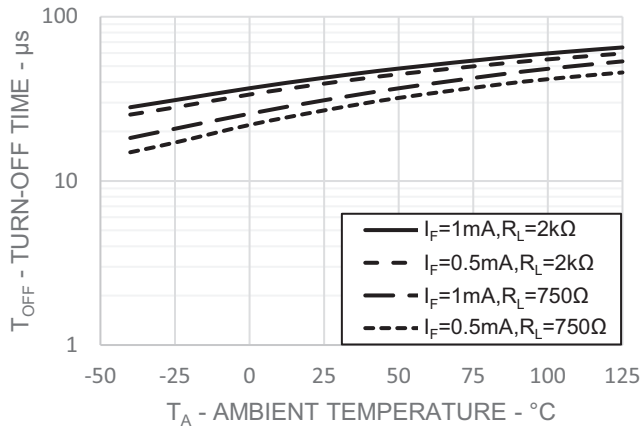
**Figure 14: Turn-Off Time vs. Load Resistance**



**Figure 15: Turn-On Time vs. Ambient Temperature**



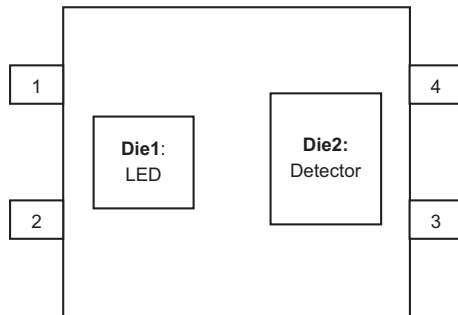
**Figure 16: Turn-Off Time vs. Ambient Temperature**



## Thermal Resistance Model for ACPL-M417T

The diagram of ACPL-M417T for measurement is shown in [Figure 17](#). This is a multi-chip package with two heat sources, the effect of heating of one die due to the adjacent dice are considered by applying the theory of linear superposition. Here, one die is heated first and the temperatures of another die are recorded after thermal equilibrium is reached. Then, the second die is heated and first die temperatures are recorded. With the known ambient temperature, the die junction temperature and power dissipation, the thermal resistance can be calculated. The thermal resistance calculation can be cast in matrix form. This yields a 2 by 2 matrix for our case of two heat sources.

**Figure 17: Thermal Resistance Measurements**



$$\begin{vmatrix} R_{11} & R_{12} \\ R_{21} & R_{22} \end{vmatrix} \times \begin{vmatrix} P_1 \\ P_2 \end{vmatrix} = \begin{vmatrix} \Delta T_1 \\ \Delta T_2 \end{vmatrix}$$

$R_{11}$ : Thermal Resistance of Die1 due to heating of Die1 (°C/W)

$R_{12}$ : Thermal Resistance of Die1 due to heating of Die2 (°C/W)

$R_{21}$ : Thermal Resistance of Die2 due to heating of Die1 (°C/W)

$R_{22}$ : Thermal Resistance of Die2 due to heating of Die2 (°C/W)

$P_1$ : Power dissipation of Die1 (W)

$P_2$ : Power dissipation of Die2 (W)

$T_1$ : Junction temperature of Die1 due to heat from all dice (°C)

$T_2$ : Junction temperature of Die2 due to heat from all dice (°C)

$T_A$ : Ambient temperature (°C)

$\Delta T_1$ : Temperature difference between Die1 junction and  $T_A$

$\Delta T_2$ : Temperature difference between Die2 junction and  $T_A$

$$T_1 = (R_{11} \times P_1 + R_{12} \times P_2) + T_A$$

$$T_2 = (R_{21} \times P_1 + R_{22} \times P_2) + T_A$$

Measurement data on a low K (conductivity) board:

$R_{11}$ : 334.4°C/W

$R_{12}$ : 95.41°C/W

$R_{21}$ : 91.56°C/W

$R_{22}$ : 175.3°C/W

Measurement data on a high K (conductivity) board:

$R_{11}$ : 257.7°C/W

$R_{12}$ : 37.24°C/W

$R_{21}$ : 30.69°C/W

$R_{22}$ : 87.95°C/W

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